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Data Sheet

November 2013

8 A, 1200 V, Hyperfast Diode

The RHRP8120 is a hyperfast diode with soft recovery characteristics. It has the half recovery time of ultrafast diodes and is silicon nitride passivated ionimplanted epitaxial planar construction. These devices are intended to be used as freewheeling/ clamping diodes and diodes in a variety of switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching transistors.

Ordering Information

PART NUMBERPACKAGEBRANDRHRP8120TO-220AC-2LRHRP8120

NOTE: When ordering, use the entire part number.

Symbol



Features

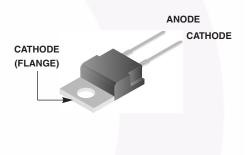
- Hyperfast Recovery t_{rr} = 70 ns (@ I_F= 8 A)
- Max Forward Voltage, V_F = 3.2 V (@ T_C = 25°C)
- 1200 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- RoHS Compliant

Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

Packaging





Absolute Maximum Ratings T_C = 25^oC, Unless Otherwise Specified

	RHRP8120	UNIT
Peak Repetitive Reverse Voltage	1200	V
Working Peak Reverse Voltage V _{RWM}	1200	V
DC Blocking Voltage	1200	V
Average Rectified Forward Current	8	A
Repetitive Peak Surge Current I _{FRM} (Square Wave, 20 kHz)	16	A
Nonrepetitive Peak Surge Current I _{FSM} (Halfwave, 1 Phase, 60 Hz)	100	А
Maximum Power Dissipation	75	W
Avalanche Energy (See Figures 10 and 11) E _{AVL}	20	mJ
Operating and Storage Temperature	-65 to 175	°C

SYMBOL	TEST CONDITION	MIN	ТҮР	MAX	UNIT
V _F	I _F = 8 A	-	-	3.2	V
	I _F = 8 A, T _C = 150 ^o C	-	-	2.6	V
I _R	V _R = 1200 V	-	-	100	μΑ
	$V_{\rm R} = 1200 \text{ V}, \text{ T}_{\rm C} = 150^{\rm O} \text{C}$	-	-	500	μΑ
t _{rr}	I _F = 1 A, dI _F /dt = 200 A/μs	-	-	55	ns
	I _F = 8 A, dI _F /dt = 200 A/μs	-	-	70	ns
t _a	I _F = 8 A, dI _F /dt = 200 A/μs	-	30	-	ns
t _b	I _F = 8 A, dI _F /dt = 200 A/μs	-	20	-	ns
Q _{rr}	I _F = 8 A, dI _F /dt = 200 A/μs	-	165	-	nC
CJ	V _R = 10 V, I _F = 0 A	-	25	-	pF
R _{θJC}		-	-	2	°C/W

Electrical Specifications $T_C = 25^{\circ}C$, Unless Otherwise Specified

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 µs, D = 2%).

I_R = Instantaneous reverse current.

 T_{rr} = Reverse recovery time (See Figure 9), summation of $t_a + t_b$.

 t_a = Time to reach peak reverse current (See Figure 9).

t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

Q_{rr} = Reverse Recovery Charge.

C_J = Junction Capacitance.

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = Pulse Width.

D = Duty Cycle.

Typical Performance Curves

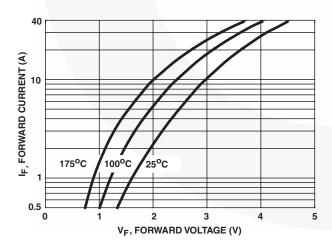


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

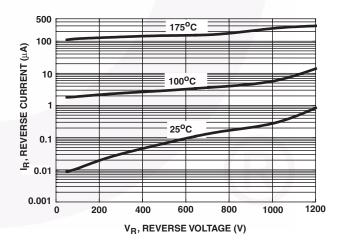


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

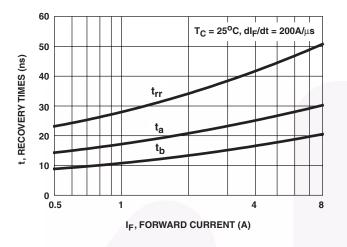
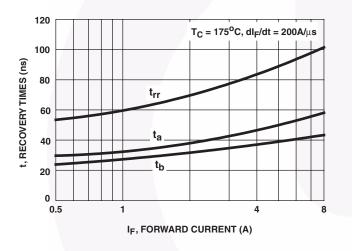


FIGURE 3. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT





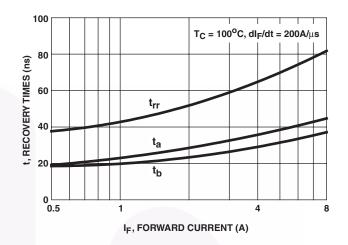


FIGURE 4. trr, ta AND tb CURVES vs FORWARD CURRENT

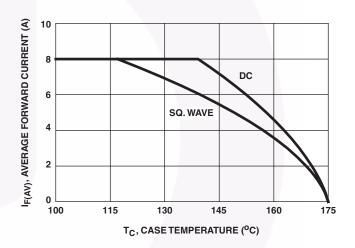


FIGURE 6. CURRENT DERATING CURVE

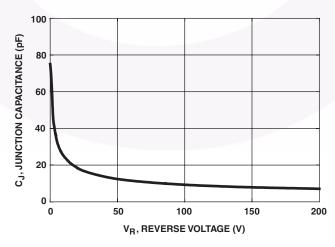
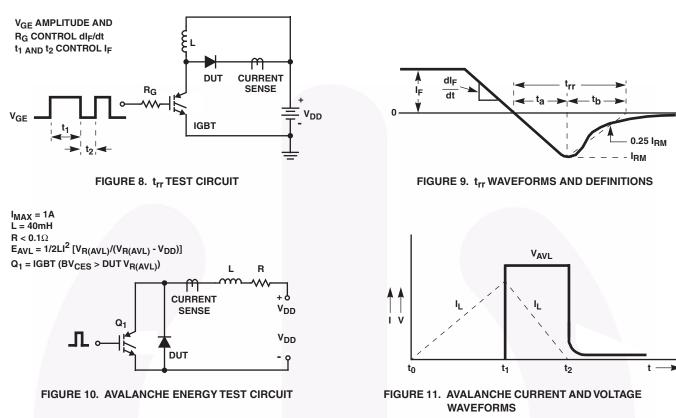


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

Test Circuits and Waveforms



Ø 4.09 3.50 ⊕ 0.36 M B A M 10.67 В Α 9.65 8.89 3.43 1.40 6.86 2.54 0.51 6.86 **7**° 5.84 3° T 13.40 16.51 12,19 14,22 16.15 9.40 15,75 8.38 **5**° **5**° 3° 3° 6.35 MAX 2 1 0.60 MAX С 14.73 13,60 1.65 (1.91)1.25 F Т 0.61 2.54 0.33 1.02 2.92 0.38 2.03 5.08 ⊕ 0.36 M C A B **5° 5°** 3° 3° -...... FAIRCHILD ... 4.80 4.30

NOTES:

- A. PACKAGE REFERENCE: JEDEC TO220,ISSUE K, VARIATION AC,DATED APRIL 2002.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSION AND TOLERANCE AS PER ASME Y14.5-2009.
- D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
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